

## Highlights

Innovative materials with strong interplay of spin orbital charge and topological degrees of freedom - 2019

### Anomalous and Polarization-Sensitive Photoresponse of $T_d$ - $WTe_2$ from Visible to Infrared Light

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Recently, an emergent layered material  $T_d$ - $WTe_2$  was explored for its novel electron-hole overlapping band structure and anisotropic inplane crystal structure. Here, the photoresponse of mechanically exfoliated  $WTe_2$  flakes is investigated. A large anomalous current decrease for visible (514.5 nm), and mid- and far-infrared (3.8 and 10.6  $\mu\text{m}$ ) laser irradiation is observed, which can be attributed to light-induced surface bandgap opening from first-principles calculations. The photocurrent and responsivity can be as large as 40  $\mu\text{A}$  and 250  $\text{A W}^{-1}$  for a 3.8  $\mu\text{m}$  laser at 77 K. Furthermore, the  $WTe_2$  anomalous photocurrent matches its in-plane crystal structure and exhibits light polarization dependence, maximal for linear laser polarization along the W atom chain  $a$  direction and minimal for the perpendicular  $b$  direction, with the anisotropic ratio of 4.9. Consistently, first-principles calculations confirm the angle-dependent bandgap opening of  $WTe_2$  under polarized light irradiation. The anomalous and polarization-sensitive photoresponses suggest that linearly polarized light can significantly tune the  $WTe_2$  surface electronic structure, providing a potential

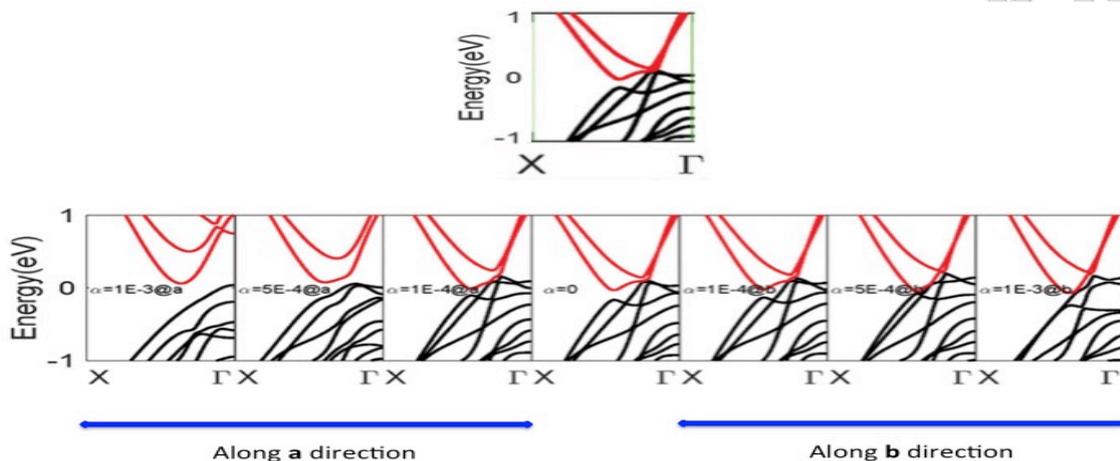


Fig. 1: The bulk  $WTe_2$  electronic structure without laser irradiation (top panel).  $WTe_2$  electronic structure along  $X$ - $\Gamma$  directions for different values of parameter  $\alpha$  when the 700 nm linear polarization direction of the light is along the  $a$  or  $b$  directions -  $\alpha$  is a parameter related to the input laser power, its physical meaning is the approach number of excitons mixed in the electrons of a unit cell (bottom panel).